

TOSHIBA Photocoupler Photorelay

TLP4176G

PBX

Telecommunication

Modem·FAX Cards, Modems In PC

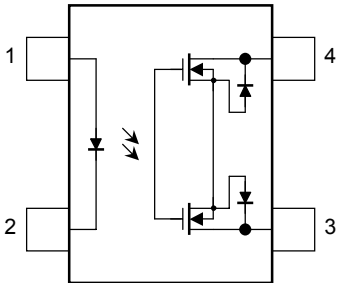
Measurement Instrumentation

The TOSHIBA TLP4176GA consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a SOP, which is suitable for surface mount assembly.

The TLP4176GA is suitable for the modem applications which require space savings.

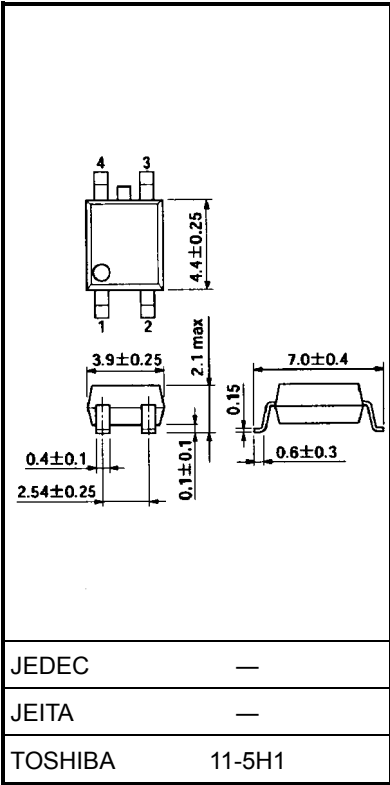
- 4 pin SOP (2.54SOP4): 2.1 mm high, 2.54 mm pitch
- 1-form-B
- Peak off-state voltage: 350 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 120 mA (max)
- On-state resistance: 25 Ω (max)
- Isolation voltage: 1500 Vrms (min)

Pin Configuration (top view)



- 1: ANODE
- 2: CATHODE
- 3: DRAIN
- 4: DRAIN

Unit: mm



Weight: 0.1 g (typ.)

## Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
LED	Forward current	$I_F$	50	mA
	Forward current derating (Ta ≥ 25°C)	$\Delta I_F/^\circ\text{C}$	-0.5	mA/°C
	Peak forward current (100 μs pulse, 100 pps)	$I_{FP}$	1	A
	Reverse voltage	$V_R$	5	V
	Junction temperature	$T_j$	125	°C
Detector	Off-state output terminal voltage	$V_{OFF}$	350	V
	On-state current	$I_{ON}$	120	mA
	On-state current derating (Ta ≥ 25°C)	$\Delta I_{ON}/^\circ\text{C}$	-1.2	mA/°C
	Junction temperature	$T_j$	125	°C
Operating temperature range		$T_{opr}$	-40 to 85	°C
Storage temperature range		$T_{stg}$	-55 to 125	°C
Lead soldering temperature (10 s)		$T_{sol}$	260	°C
Isolation voltage (AC, 1 min, R.H. ≤ 60%) (Note 1)		$BV_S$	1500	Vrms

Note 1: Device considered a two-terminal device: LED side pins shorted together, and DETECTOR side pins shorted together.

## Recommended Operating Conditions

Characteristics	Symbol	Min	Typ.	Max	Unit
Supply voltage	$V_{DD}$	—	—	280	V
Forward current	$I_F$	5	—	25	mA
On-state current	$I_{ON}$	—	—	120	mA
Operating temperature	$T_{opr}$	-20	—	65	°C

## Individual Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	$V_F$	$I_F = 10\text{ mA}$	1.0	1.15	1.3	V
	Reverse current	$I_R$	$V_R = 5\text{ V}$	—	—	10	μA
	Capacitance	$C_T$	$V = 0, f = 1\text{ MHz}$	—	30	—	pF
Detector	Off-state current	$I_{OFF}$	$V_{OFF} = 350\text{ V}, I_F = 5\text{ mA}$	—	—	1	μA
	Capacitance	$C_{OFF}$	$V = 0, f = 1\text{ MHz}, I_F = 5\text{ mA}$	—	—	—	pF

## Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current	$I_{FC}$	$I_{OFF} = 10\text{ μA}$	—	1	3	mA
Return LED current	$I_{FT}$	$I_{ON} = 120\text{ mA}$	0.1	—	—	mA
On-state resistance	$R_{ON}$	$I_{ON} = 120\text{ mA}$	—	15	25	Ω

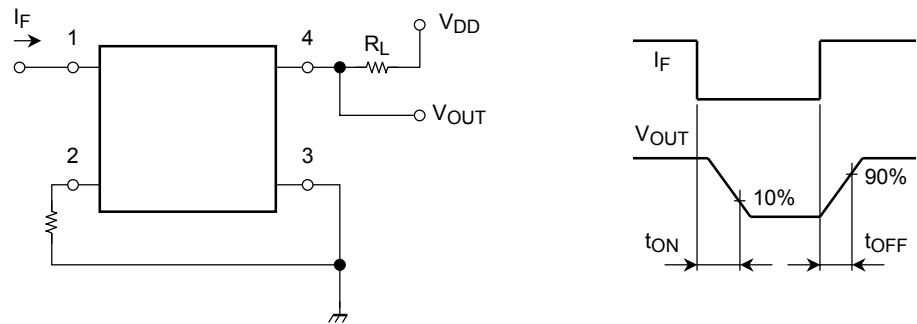
Isolation Characteristics (Ta = 25°C)

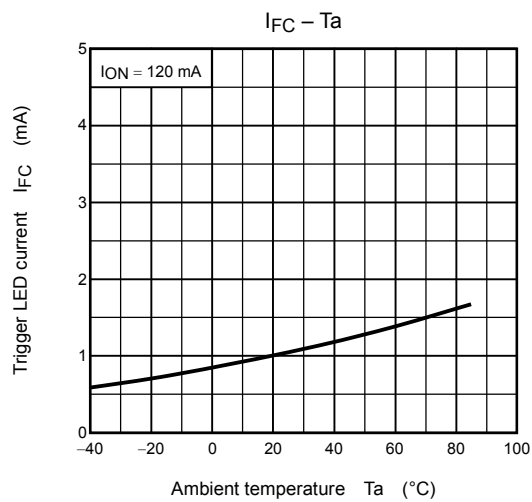
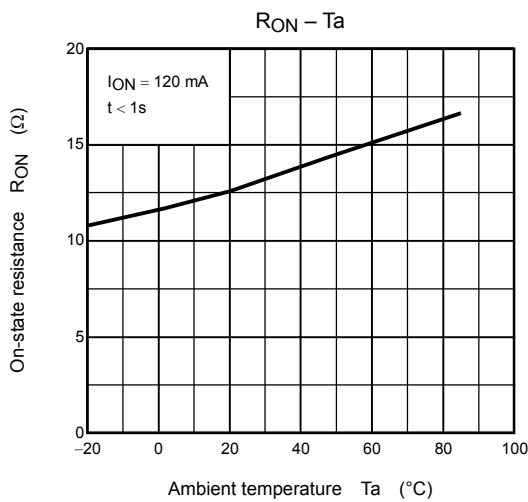
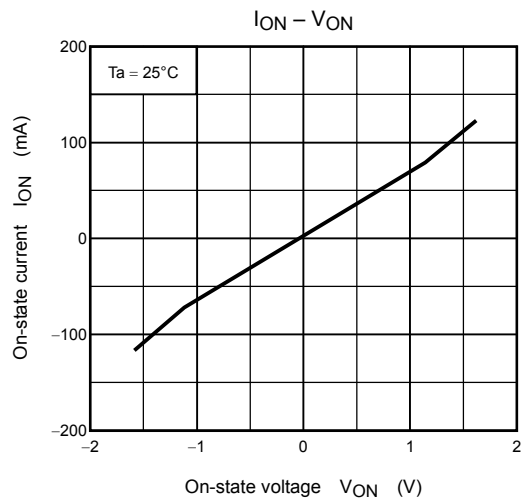
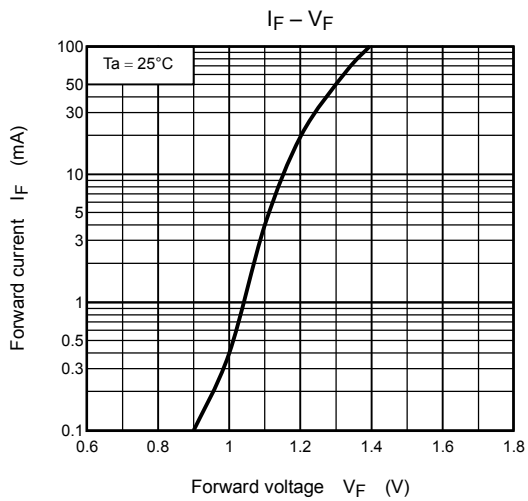
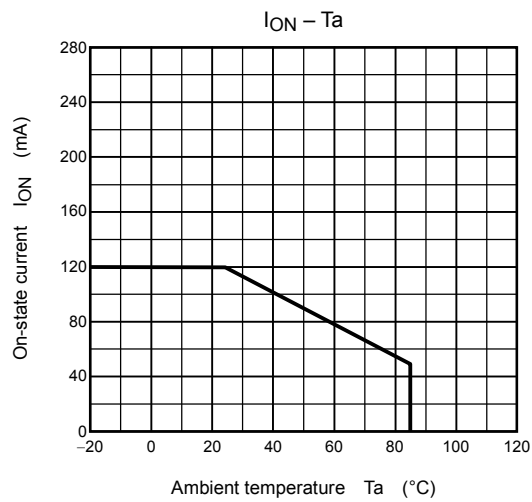
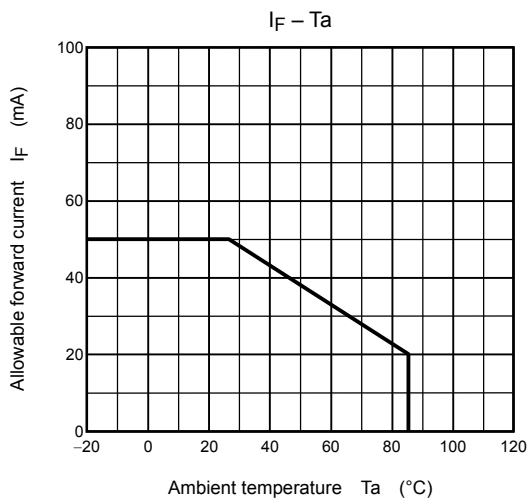
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output	CS	VS = 0, f = 1 MHz	—	0.8	—	pF
Isolation resistance	RS	VS = 500 V, R.H. ≤ 60%	$5 \times 10^{10}$	$10^{14}$	—	Ω
Isolation voltage	BVS	AC, 1 min	1500	—	—	Vrms
		AC, 1 s, in oil	—	3000	—	
		DC, 1 min, in oil	—	3000	—	Vdc

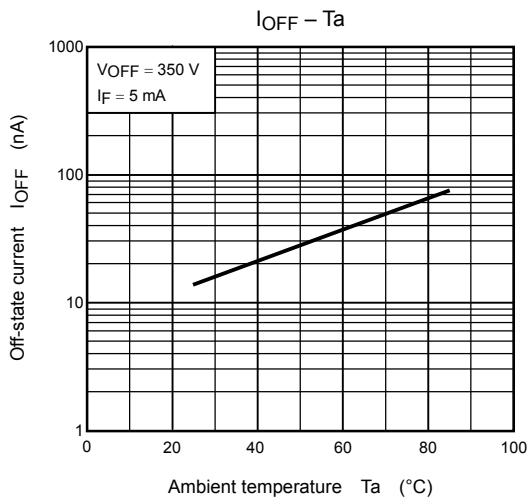
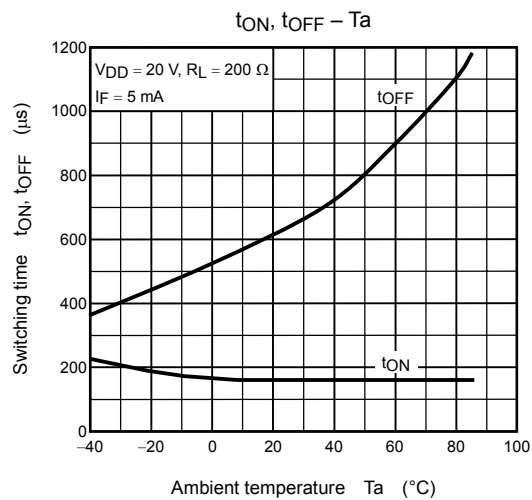
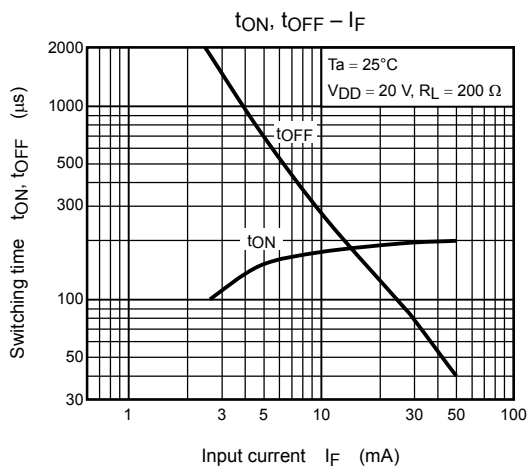
Switching Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Turn-on time	tON	RL = 200 Ω (Note 2)	—	—	1	ms
Turn-off time	tOFF	VDD = 20 V, IF = 5 mA	—	—	3	ms

Note 2: Switching time test circuit







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